

$I_{F(AV)} = 0.2\text{Amp}$
 $V_R = 30\text{V}$

Major Ratings and Characteristics

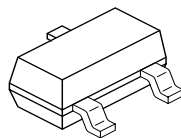
Characteristics	Value	Units
I_F (DC)	0.2	A
V_{RRM}	30	V
I_{FSM} @ $t_p = 10\text{ms}$ sine	1.0	A
V_F @ 30mA DC, $T_J = 25^\circ\text{C}$	0.5	V
P_d Power Dissipation @ $T_A = 25^\circ\text{C}$	200	mW
T_J range	- 65 to 150	$^\circ\text{C}$

Description/ Features

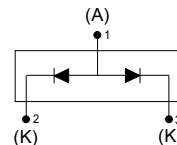
This Schottky barrier diode is designed for high speed switching application, voltage clamping and circuit protection. Miniature surface mount packages with reduced foot print are excellent for portable application where space is limited

- Small foot print, surface mountable
- Very low forward voltage drop
- Extremely fast switching speed for high frequency operation
- Guard ring for enhanced ruggedness and long term reliability

Case Styles



SOT323



Voltage Ratings

Part number	Value
V_R Max. DC Reverse Voltage (V)	30
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	Value	Units	Conditions	
I_F Forward Current	0.2	A	DC, per Leg	
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current, @ $T_J = 25^\circ\text{C}$	8.4	A	5 μs Sine or 3 μs Rect. pulse	Following any rated load condition and with rated V_{RWM} applied
	1.0	A	10ms Sine or 6ms Rect. pulse	

Electrical Specifications

Parameters	Value	Units	Conditions	
V_{FM} Max. Forward Voltage Drop (1)	0.24	V	@ 0.1mA	$T_J = 25^\circ\text{C}$
	0.32	V	@ 1mA	
V_{FM} Max. Forward Voltage Drop (1)	0.40	V	@ 10mA	
	0.50	V	@ 30mA	
	0.65	V	@ 100mA	
I_{RM} Max. Reverse Leakage Current (1)	2	μA	$V_R = 25\text{V}$	
	3	μA	$V_R = 30\text{V}$	
C_T Max. Junction Capacitance	10	pF	$V_R = 1V_{DC}$ (test signal range 100kHz to 1Mhz), $T_J = 25^\circ\text{C}$	
dv/dt Max. Voltage Rate of Change (Rated V_R)	10000	V/ μs		

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Value	Units	Conditions
T_J Max. Junction Temperature Range(*)	-65 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 150	$^\circ\text{C}$	
$R_{th(j-a)}$ Max. Thermal Resistance Junction to Ambient	625	$^\circ\text{C/W}$	Mounted on PC board FR4 with minimum pad size
Wt Approximate Weight	0.006	gr	
Case Style	SOT323		
Device Marking	JYWLC		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

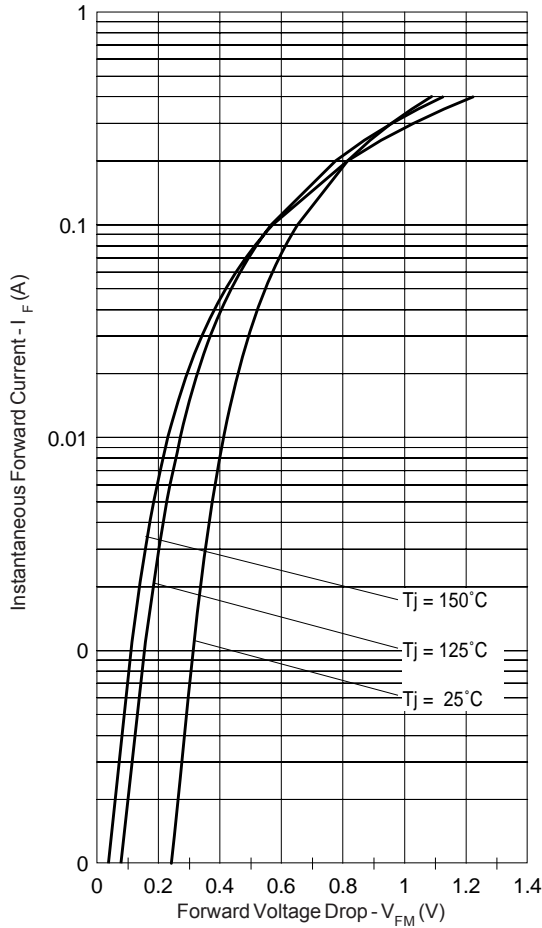


Fig. 1 - Max. Forward Voltage Drop Characteristics (Per Leg)

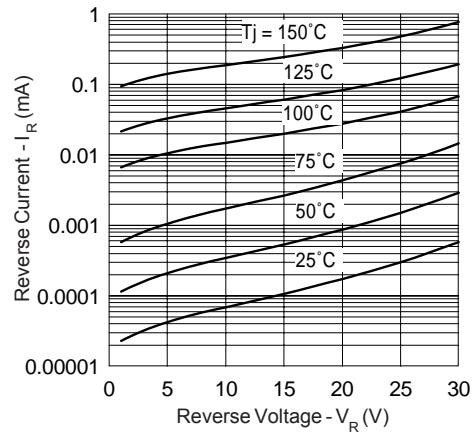


Fig. 2 - Typical Values Of Reverse Current Vs. Reverse Voltage (Per Leg)

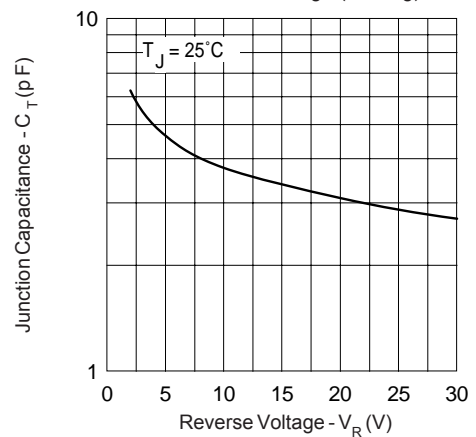


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage (Per Leg)

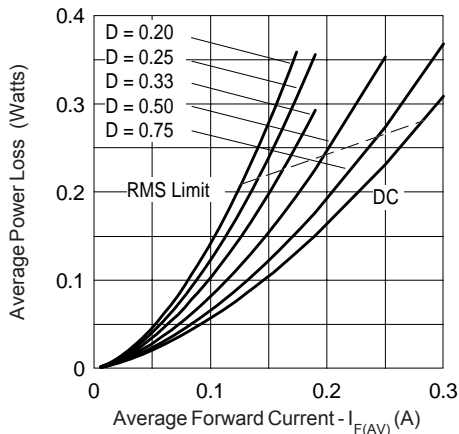


Fig. 4 - Forward Power Loss Characteristics

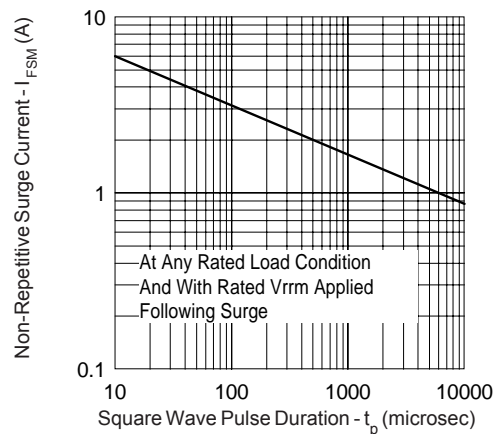
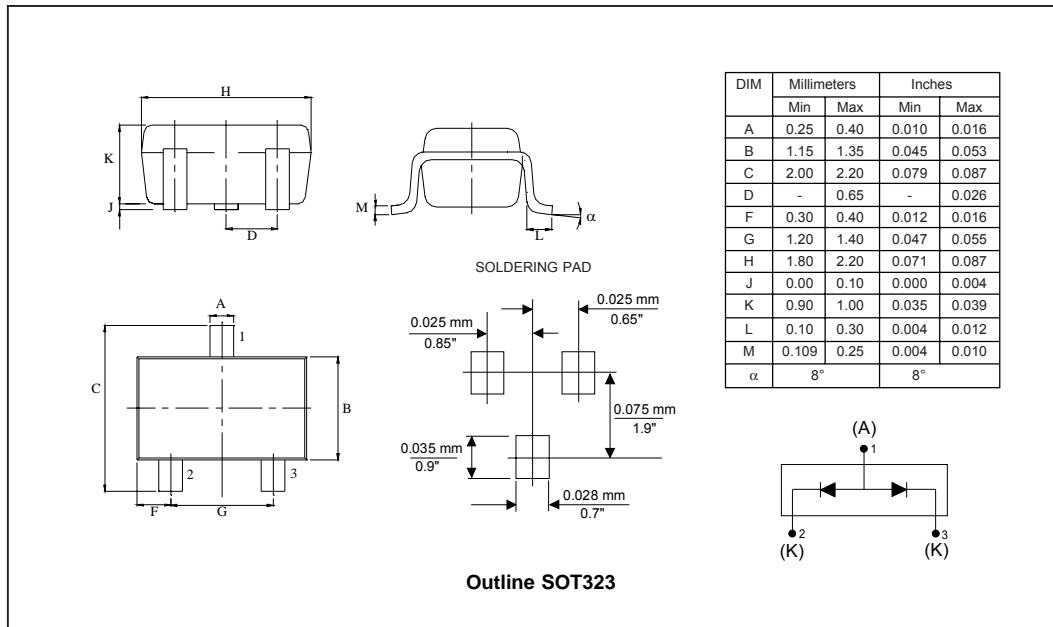
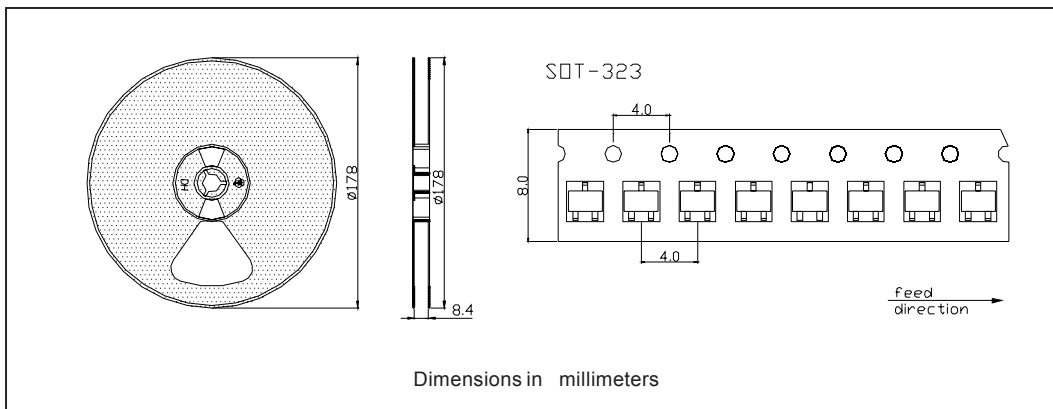


Fig. 5 - Max. Non-Repetitive Surge Current

Outline Table



Tape & Reel Information



Ordering Information Table

Device	Package	Marking	Configuration	Base qty	Delivery mode
BAT54AW	SOT-323	JYWLC	Dual C. Anode	3000	Tape & Reel

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

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